

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Wendell P. Noble Jr. et al.
Serial No.: 09/866938
Filed: May 29, 2001
Title: ULTRA HIGH DENSITY FLASH MEMORY

Examiner: Jack Chen
Group Art Unit: 2813
Docket: 303.330US3

COMMUNICATION CONCERNING CO-PENDING APPLICATION(S)

Commissioner for Patents
P.O.Box 1450
Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related pending application(s) in the above-identified patent application:

<u>Serial No.</u>	<u>Filing Date</u>	<u>Attorney Docket</u>	<u>Title</u>
09/527981	March 17, 2000	303.322US2	FOUR F2 FOLDED BIT LINE DRAM CELL STRUCTURE HAVING BURIED BIT AND WORD LINES
09/551027	April 17, 2000	303.379US2	CIRCUIT AND METHOD FOR A FOLDED BIT LINE MEMORY CELL WITH VERTICAL TRANSISTOR AND TRENCH CAPACITOR
09/730245	December 5, 2000	303.380US3	CIRCUIT AND METHOD FOR AN OPEN BIT LINE MEMORY CELL WITH A VERTICAL TRANSISTOR AND TRENCH PLATE TRENCH CAPACITOR
09/467992	December 20, 1999	303.389US2	CIRCUITS WITH A TRENCH CAPACITOR HAVING MICRO-ROUGHENED SEMICONDUCTOR SURFACES
09/879592	June 12, 2001	303.412US2	VERTICAL GAIN CELL AND ARRAY FOR A DYNAMIC RANDOM ACCESS MEMORY AND METHOD FOR FORMING THE SAME

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Page 2
Dkt: 303.330US3

09/879602 June 12, 2001 303.412US3

VERTICAL GAIN CELL AND ARRAY
FOR A DYNAMIC RANDOM ACCESS
MEMORY AND METHOD FOR
FORMING THE SAME

10/361986 February 11, 2003 303.380US4

CIRCUIT AND METHOD FOR AN OPEN
BIT LINE MEMORY CELL WITH A
VERTICAL TRANSISTOR AND TRENCH
PLATE TRENCH CAPACITOR

Respectfully submitted,

WENDELL P. NOBLE JR. ET AL.

By Applicants' Representatives,

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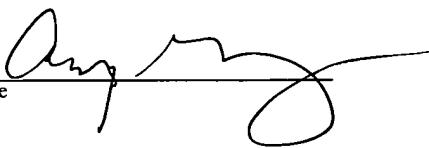
Date July 23, 2003 By

Daniel J. Kluth
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Name Amy Moriarty

Signature



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19p 28136

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Alexandria, VA 22313-1450



We are transmitting herewith the following attached items (as indicated with an "X"):

- A return postcard.
- An Amendment and Response (21 Pages).
- A Terminal Disclaimer (2 pgs.).
- A check in the amount of \$110.00 to cover the fee required to file a Terminal Disclaimer.
- A Communication Concerning Co-Pending Application(s) (2pgs).

Please consider this a PETITION FOR EXTENSION OF TIME for sufficient number of months to enter these papers and please charge any additional fees or credit overpayment to Deposit Account No. 19-0743.

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A.

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By: Daniel J. Kluth

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Reg. No. 32,146

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